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DMN2992UFB4

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Footprint of Just 0.6mm² – Thirteen Times Smaller than SOT23

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please

Package Material: Molded Plastic, "Green" Molding Compound;

Terminals: Finish - NiPdAu over Copper Leadframe; Solderable

Halogen and Antimony Free. "Green" Device (Note 3)

0.4mm Profile - Ideal for Low Profile Applications

contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

per MIL-STD-202, Method 208 @

Features and Benefits

Low Gate Threshold Voltage

Fast Switching Speed

Mechanical Data

Package: X2-DFN1006-3

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	0.99Ω @ V _{GS} = 4.5V	0.83A
20V	1.2Ω @ V _{GS} = 2.5V	0.75A
	1.8Ω @ V _{GS} = 1.8V	0.61A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

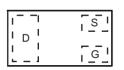
Load switches



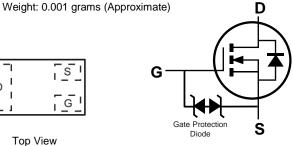
X2-DFN1006-3



Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Fart Number	Package	Qty.	Carrier	
DMN2992UFB4-7B	X2-DFN1006-3	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/guality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free. "Green" and l ead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

DMN2992UFB4-7B	Top View Bar Denotes Gate and Source Side	 BT = Product Type Marking Code
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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	20	V
Gate-Source Voltage			Vgss	±8	V
Continuous Drain Current (Note 5) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	0.83 0.66	А
Maximum Continuous Body Diode Forward Current (Note 5)			ls	0.84	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	1.52	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)		PD	0.38	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	328	°C/W
Total Power Dissipation (Note 5)		PD	1.02	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	122	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)				•		•	
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current (TJ = +25°C)	IDSS	_	_	100	nA	V _{DS} = 16V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±200	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	0.4	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
			0.42	0.99		$V_{GS} = 4.5V, I_D = 100mA$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	0.52	1.2	Ω	$V_{GS} = 2.5V, I_D = 50mA$	
			0.65	1.8		$V_{GS} = 1.8V, I_D = 20mA$	
Diode Forward Voltage	Vsd		0.7	1.0	V	V _{GS} = 0V, I _S = 150mA	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	15.6	—	pF		
Output Capacitance	Coss	_	5.4	—	pF	VDS = 16V, VGS = 0V f = 1.0MHz	
Reverse Transfer Capacitance	Crss		4	—	pF	1 - 1.00012	
Total Gate Charge	Qg		0.41	_	nC		
Gate-Source Charge	Q _{gs}	_	0.07	—	nC	VGS = 4.5V, VDS = 10V - ID = 250mA	
Gate-Drain Charge	Q _{gd}		0.12	_	nC		
Turn-On Delay Time	tD(ON)		1.77	_	ns		
Turn-On Rise Time	t _R	-	4.5	—	ns	$\nabla_{DD} = 10V, V_{GS} = 4.5V$ $R_{L} = 47\Omega, R_{G} = 10\Omega$ $-I_{D} = 200mA$	
Turn-Off Delay Time	tD(OFF)		22	_	ns		
Turn-Off Fall Time	tF	_	8.2	—	ns		

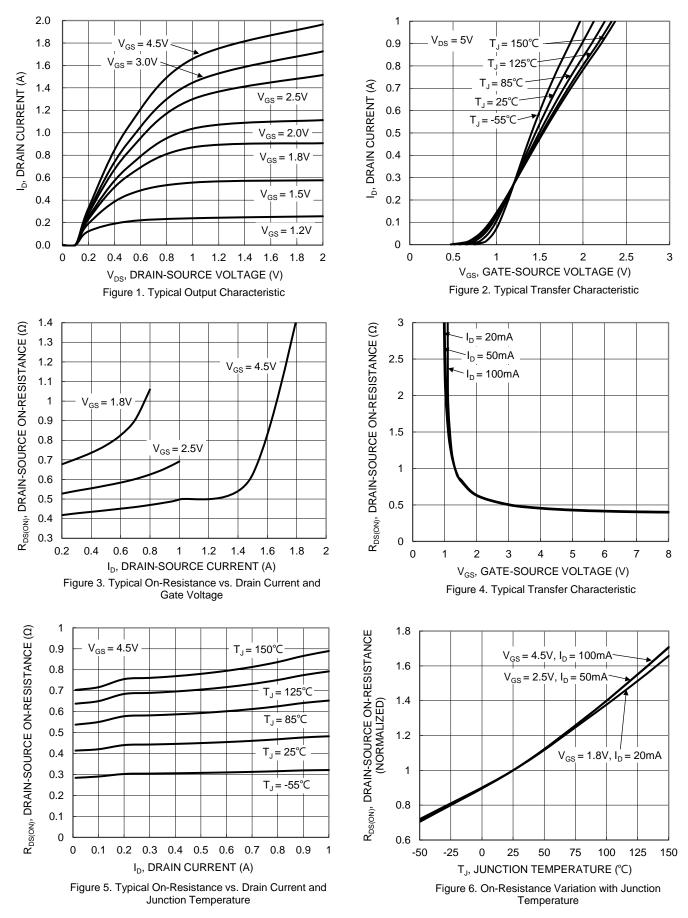
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

Device mounted on FR-4 substrate PC board, 222 copper, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.

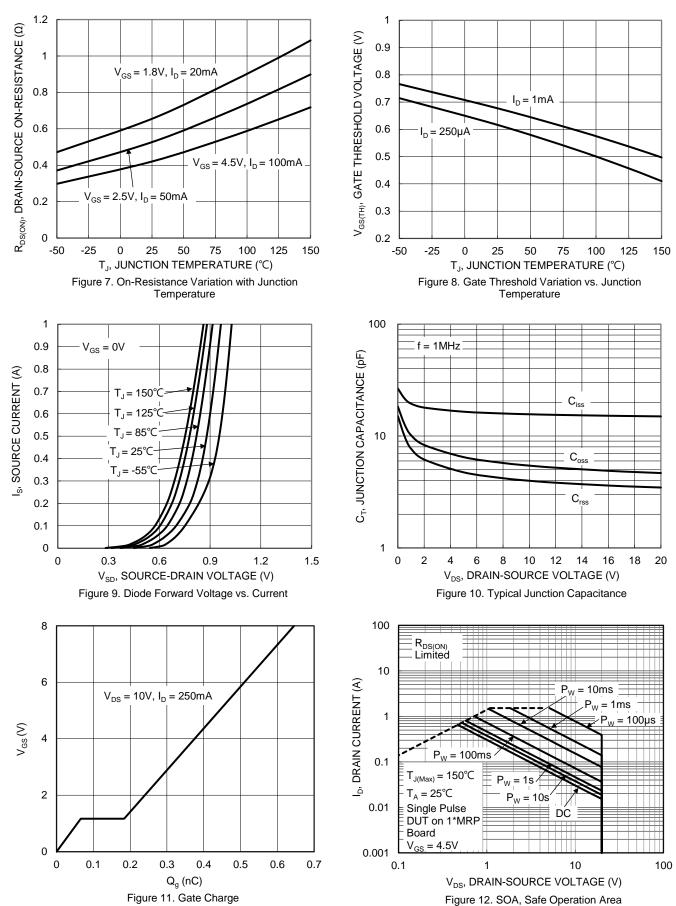
8. Guaranteed by design. Not subject to product testing.



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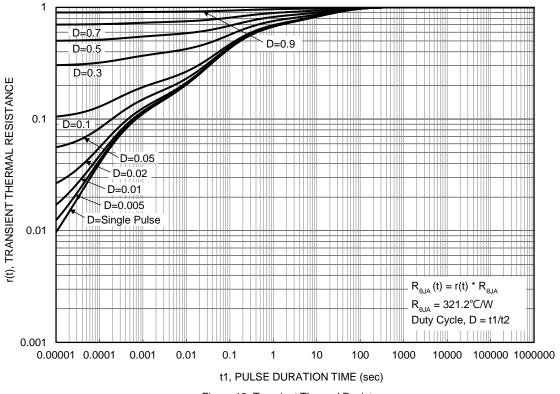


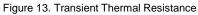




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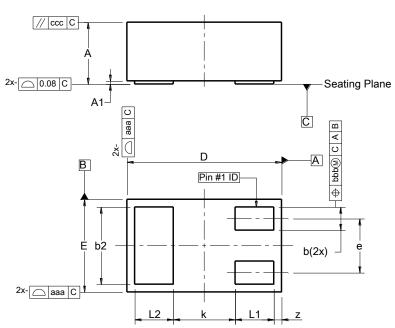






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

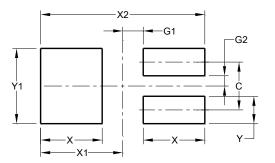


X2-DFN1006-3					
Dim	Min	Max	Тур		
Α		0.40			
A1	0.00	0.05	0.03		
b	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
Ε	0.55	0.65	0.60		
e	-	-	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
k	1	-	0.40		
Z	0.02	0.08	0.05		
aaa	0.15				
bbb	0.05				
CCC	0.05				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1006-3



Dimensions	Value (in mm)
С	0.350
G1	0.150
G2	0.075
Х	0.450
X1	0.600
X2	1.200
Y	0.200
Y1	0.550

X2-DFN1006-3



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